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### Micron-gap thermophotovoltaic systems enhanced by nanowires

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#### Abstract

We introduce new micron-gap thermophotovoltaic systems enhanced by tungsten nanowires. We theoretically show that these systems allow the frequency-selective super-Planckian spectrum of radiative heat transfer that promises a very efficient generation of electricity. Our system analysis covers practical aspects such as output power per unit area and efficiency of the tap water cooling. © 2014 Published by Elsevier B.V.

Keywords: Wire metamaterial; Hyperbolic metamaterial; Radiative heat transfer; Thermophotovoltaic system; Photovoltaic efficiency

#### 13 **1. Introduction**

As an estimate, up to 50% of the energy involved 14 in the industrial processes finally delivers as waste heat. 15 Mankind needs to exploit this energy to generate electric 16 power. It can be done indirectly, e.g. via vapor (Stirling's) machinery, or directly. Several methods of the 18 heat-electricity conversion are known: thermoelectric, 10 pyroelectric, thermophotovoltaic, and thermophotogal-20 vanic. Unlike Stirling's machines such direct generators 21 do not have moving parts and no permanent technical 22 service is needed. Thermophotovoltaic (TPV) conver-23 sion has attracted significant attention from the research 24 community in the last decade [1] due to its potentially 25 highest efficiency. TPV systems are based on the photo-26 voltaic (PV) effect manifested by the photocurrent. The 27 PV cell absorbs the thermal radiation produced by the 28 rear side of emitter whose front side is connected to the 29

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http://dx.doi.org/10.1016/j.photonics.2014.10.007 1569-4410/© 2014 Published by Elsevier B.V. heat source, e.g. flame, see in Fig. 1. For high temperatures of the emitter, corresponding to the near-infrared radiation (NIR), the TPV efficiency is higher compared to other known mechanisms of the direct heat-electricity conversion [2]. Not only wasted heat can be converted, using TPV devices. TPV generators with combustion cameras are also prospective for the domestic use [1,2].

In spite of striking advantages of TPV devices as electric generators, a key problem of these systems is a disappointing gap between the maximally achievable and practically achieved operation parameters. For given temperatures of the emitter and the PV panel the electric power output per unit area (p.u.a.) of any known TPV system is much below its theoretically possible maximum [3]. One of main reasons of this situation is non-advantageous, extremely broad spectrum of emitted radiation. It is commonly (and incorrectly [4]) adopted that the maximal thermal radiation in all possible situations is radiation of a black body to free space. Therefore, the emitters mimicking the black body are often considered as best ones. The spectrum of its radiation has relative bandwidth (BW) which, defined on the 10% level, exceeds 500% even for temperature as high as 2

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Fig. 1. Principle of a TPV system.

2000 °K. The operational band of a PV semiconductor 53 is much narrower - its BW is nearly 100%. Therefore, 54 a large amount of thermal radiation in a TPV system is 55 unusable [5]. The radiation at frequencies below that of 56 the semiconductor bandgap is completely harmful. At 57 these frequencies, all thermal photons transmitted to the 58 PV medium are dissipated and heat the PV panel destroy-59 ing its operation. The PV operational band is narrower 60 than the upper half of the thermal radiation spectrum 61 (that above the bandgap frequency). Thus, the frequen-62 cies of thermal radiation which are twofold and greater 63 than the bandgap frequency are also fully harmful. The 64 harmful action of the unusable spectrum is prevented in 65 TPV systems with optical filters. These filters, roughly 66 speaking, transmit only a useful part of the spectrum 67 removing the reflection in this band. The harmful radi-68 ation is reflected. As a rule, these filters represent a 69 multi-layer structure of transparent dielectrics [1,2]. It 70 is clear that filtering though allows a TPV system to 71 operate does not solve the problem of losses. 72

Avoiding these losses is possible by squeezing the 73 radiation spectrum compared to that of a black body. This 74 regime may be offered by a frequency-selective emitter. 75 Its radiation spectrum in the ideal case should mimic that 76 of a black body within the PV operational band and van-77 ish beyond it. Using frequency-selective emitters, one 78 achieves high values of the TPV efficiency – up to 20% 79 (see e.g. in [6]). Such advanced emitters may be based 80 on photonic crystals or metamaterials. Particularly high 81 TPV efficiency – up to 40% – is theoretically achieved 82 for solar TPV systems, where advanced emitters also 83 serve perfect absorbers of the sunlight [7–9]. However, 84 the total radiation of any known advanced emitters over 85 the PV operational band is noticeably lower than the 86 Planckian limit. Practically, the spectrum of a metama-87 terial thermal emitter attains the black-body spectrum 88

only at resonant frequency. Also, beyond the operational band the thermal radiation of these emitters is not negligible. Therefore, the electric power output p.u.a. in these systems is not very high. For emitters with temperatures  $T^{(1)} = 2000 \,^{\circ}$ K this value in theoretical estimates [7–9] corresponds to  $1.5-2 \,$ W/cm<sup>2</sup> that is only twice as higher as that achieved in best available TPV systems operating at the same temperature [10].

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## 2. Micron-gap TPV systems enhanced by hyperbolic metamaterials

Recently, advanced TPV systems were introduced: so-called near-field systems comprising a nanogap between the PV medium and the emitter (see e.g. in [11]) and micron-gap ones fabricated by stacking the PV panel and the emitter separated by micron (or slightly submicron) spacers (see e.g. in [12,13]). They possess so-called super-Planckian (SP) radiative heat transfer (RHT). In a micron-gap TPV system the emitter transfers to the PV panel more power p.u.a. than the black body of the same temperature may do. The gain compared to a black-body emitter may be twofold and occurs due to the so-called photon tunneling effect [2,5,11,14]. In a near-field TPV system the photon tunneling is stronger and the gain compared to the black body may attain 3-4 orders of magnitude (see e.g. in [2,11]). Unfortunately, the concept of a TPV filter is very difficult to implement for these advanced TPV systems: the RHT decays across a filter and the SP effect is lost. Therefore, in spite of high radiation fluxes, higher electric output compared to conventional TPV systems has not been claimed for these advanced devices. Avoiding the harmful heating by unusable radiation, near-field TPV systems are only applied in the range of low, e.g. room, temperatures. Their practical purpose is temperature sensing [2,3,11].

An actual target for specialists in TPV systems is to develop a frequency-selective emitter compatible with the concept of a near-field or a micron-gap TPV system. More specifically (since the emitter characteristics cannot be determined separately in such devices), one has to create TPV systems which offer the frequency-selective SP RHT. In the PV operational band this RHT should be above the Planckian limit and beyond this range - sufficiently weak. Recently, some papers appeared on such a frequency-selective SP RHT in a near-field TPV system (e.g. [15]). However, we concentrate on micron-gap TPV systems. The latter ones are more suitable for the generation of electricity because (unlike near-field TPV systems) they can be implemented on macroscopic area - as large as few cm<sup>2</sup> - whereas the gap between the emitting and cold (PV) surfaces can be as tiny as 500 nm

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